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[54]	Title:	PHOTOELECTRIC CONVERSION DEVICE, IMAGE PICKUP SYSTEM, AND DRIVING METHOD OF THE PHOTOELECTRIC CONVERSION DEVICE	
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[57]	Abstract:	A photoelectric conversion device has a pixel area including an effective pixel row and a reference pixel row, the reference pixel row containing a plurality of reference pixel pairs, each pair composed of a first reference pixel and a second reference pixel arranged adjacent to each other. The first and second reference pixels output reference signals having different signal levels and independent of the quantity of incident light.	

TITLE OF THE INVENTION

PHOTOELECTRIC CONVERSION DEVICE, IMAGE PICKUP SYSTEM, AND
DRIVING METHOD OF THE PHOTOELECTRIC CONVERSION DEVICE

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BACKGROUND OF THE INVENTION

Field of the Invention

The present invention relates to a photoelectric
10 conversion device, and particularly relates to a
photoelectric conversion device that outputs a
reference signal.

Description of the Related Art

In the field of image pickup apparatuses, a signal
15 serving as a reference for timing of an operation, such
as correction, is known to be generated by an image
pickup apparatus itself. Japanese Patent Laid-Open No.
5-308579 describes a technique in which an optical black
region containing light shielded pixels includes position
20 reference pixels that generate output signals different
from those generated by the light shielded pixels. Also,
Japanese Patent Laid-Open No. 5-308579 mentions that one
position reference pixel is surrounded by light shielded
pixels.

25 In a solid-state imaging apparatus described in
Japanese Patent Laid-Open No. 5-308579, the output of
position reference pixels may vary depending on, for
example, the temperature, the use environment, or the
length of storage time of the solid-state imaging
30 apparatus. In particular, since one position reference
pixel in the optical black region is surrounded by
light shielded pixels, it is difficult to identify

whether the read signal is based on the position
reference pixel or is a specific signal generated by a
defective light shielded pixel or the like. Also, since
one position reference pixel is surrounded by light
5 shielded pixels, a complex process is required to
identify the start position of a row from read signals.

SUMMARY OF THE INVENTION

Techniques to be described below solve at least
one of the problems described above.

10 A photoelectric conversion device according to an
aspect of the present invention has a pixel area
including an effective pixel row and a reference pixel
row, the reference pixel row containing a plurality of
reference pixel pairs, each pair composed of a first
15 reference pixel and a second reference pixel arranged
adjacent to each other. The first reference pixel
outputs a first reference signal independent of the
quantity of incident light. The second reference pixel
outputs a second reference signal having a signal level
20 different from a signal level of the first reference
signal. The second reference signal is also independent
of the quantity of incident light.

A driving method of a photoelectric conversion
device according to another aspect of the present
25 invention is a driving method of a photoelectric
conversion device having a pixel area including an
effective pixel row and a reference pixel row, the
reference pixel row containing a plurality of reference
pixel pairs and a light shielded pixel, each pair
30 composed of a first reference pixel and a second
reference pixel arranged adjacent to each other,

wherein the first reference pixel outputs a first reference signal independent of the quantity of incident light, and the second reference pixel outputs a second reference signal having a signal level
5 different from a signal level of the first reference signal, the second reference signal being independent of the quantity of incident light. The driving method includes outputting a signal from each of the first reference pixel and the second reference pixel included
10 in one of the pairs before the light shielded pixel outputs a signal.

Further features of the present invention will become apparent from the following description of exemplary embodiments with reference to the attached
15 drawings.

BRIEF DESCRIPTION OF THE DRAWINGS

FIG. 1 illustrates a configuration of a photoelectric conversion device.

FIG. 2A illustrates a configuration of a reference
20 pixel row and FIG. 2B illustrates a signal output from an output unit according to a first embodiment.

FIG. 3A illustrates a configuration of an effective pixel and FIG. 3B illustrates a configuration of a first reference pixel according to the first
25 embodiment.

FIG. 4A illustrates a configuration of a reference pixel row and FIG. 4B illustrates a signal output from the output unit according to a second embodiment.

FIG. 5 illustrates a configuration of a reference
30 pixel according to a third embodiment.

FIG. 6 illustrates a configuration of an image pickup system according to a fourth embodiment.

DESCRIPTION OF THE EMBODIMENTS

First Embodiment

5 FIG. 1 illustrates a configuration of a photoelectric conversion device according to a first embodiment. A photoelectric conversion device 1 includes a pixel area PA, a row selecting unit 400, a reading unit 500, an output unit 600, and a horizontal
10 scanning unit 700.

 The pixel area PA includes an effective pixel region 100, a light shielded pixel region 200, and a reference pixel region 300. The effective pixel region 100 includes an effective pixel row containing a
15 plurality of effective pixels, each including a photoelectric converter and configured to output a signal in accordance with incident light. The light shielded pixel region 200 includes a light shielded pixel row containing a plurality of light shielded
20 pixels, each including a photoelectric converter shielded from light.

 When the row selecting unit 400 selects a row in the pixel area PA, pixel signals are output from pixels in the selected row. In conjunction with the horizontal
25 scanning unit 700, the reading unit 500 multiplexes signals output in parallel from the pixel area PA, and outputs the multiplexed signal from the output unit 600. The reading unit 500 may include a circuit that buffers signals output from the pixel area PA, and
30 a sample-and-hold circuit that samples and holds signals output from the pixel area PA.

FIG. 2A illustrates a configuration of a reference pixel row included in the reference pixel region 300. A reference pixel row of the present embodiment contains a plurality of reference pixel pairs 33, each composed of a first reference pixel 30 and a second reference pixel 31 arranged adjacent to each other. In the present embodiment, the reference pixel pairs 33 are disposed at both ends of the reference pixel row. The first reference pixel 30 and the second reference pixel 31 in each of the reference pixel pairs 33 at both ends are arranged in this order from the corresponding end. A first reference signal output from the first reference pixel 30 and a second reference signal output from the second reference pixel 31 have different signal levels. Both the first and second reference signals are independent of the quantity of light incident on the photoelectric conversion device 1. The reference pixel row may contain not only the reference pixel pairs 33, but also other pixels. FIG. 2A illustrates an example where the reference pixel row contains light shielded pixels in a region except a region of four pixels at each end of the reference pixel row.

FIG. 2B shows a transition of the value of a signal output from the output unit 600 when signals of a reference pixel row are read. Here, a description will be given of the case where signals are sequentially read from the left-hand side of FIG. 2A. In the period from time T_0 to time T_4 in FIG. 2B, the first reference signal having an output level V_1 and the second reference signal having an output level V_2 are alternately output twice each. In the period from time T_4 to time T_{N-4} , a signal based on the light shielded pixels 200 is output. Then, in the period from

time T_{N-4} to time T_N , the second reference signal and the first reference signal are alternately output twice each. The output level V_2 of the second reference signal may be substantially the same as the level of the signal output from the light shielded pixels 200 as shown in FIG. 2B, or may be different from the level of the signal output from the light shielded pixels 200. Here, the "substantially the same" level means that even if there is a difference in signal level, the difference is within a negligible range. The range of the "substantially the same" level varies depending on the application of the photoelectric conversion device 1 or the specifications to be met.

When a reference pixel row contains a plurality of reference pixel pairs 33 as described above, a transition from a first reference level to a second reference level or a transition from a second reference level to a first reference level appears multiple times in a signal output from the reference pixel row. This facilitates identification of a signal based on a reference pixel. In particular, when a plurality of reference pixel pairs 33 are arranged adjacent to each other, an output pattern is obtained in which the first and second reference signals alternately appear. This makes it possible to accurately distinguish a signal based on a reference pixel from an accidentally generated signal based on a defect in the light shielded pixels 200. Even when, for example, a light shielded pixel, instead of a reference pixel, is disposed at a physical end of a reference pixel row, the beginning of the reference pixel row can be identified by first selecting a reference pixel pair 33 in scanning of the reference pixel row. In

other words, each of a first reference pixel and a second reference pixel included in a reference pixel pair 33 outputs a signal before a light shielded pixel contained in the reference pixel row outputs a signal.

5 The photoelectric conversion device 1 may perform scanning not only in one direction of the pixel area PA, but also in the opposite direction thereof. By providing a reference pixel pair 33 at an end of a reference pixel row, that is, at the scanning start
10 position, the start position of the pixel row being read can be identified. Additionally, in the present embodiment, the first and second reference pixels 30 and 31 of the reference pixel pair 33 disposed at each end of a reference pixel row
15 are arranged in this order from the corresponding end. Thus, the start of the pixel row can be accurately identified even when the direction of scanning is changed. In particular, if a configuration is made such that the output unit 600 outputs a signal level
20 equivalent to that of the second reference signal when no pixel is selected or after one row is read, a signal level equivalent to that of the second reference signal is always output before a signal is read from a reference pixel row. Therefore, by first selecting the
25 first reference pixel 30 in a reference pixel row, the start of the pixel row can be more easily identified.

FIG. 3A illustrates a configuration of an effective pixel 10 in the effective pixel region 100. The effective pixel 10 includes a photoelectric
30 converter PD, transistors M1 and M2, and a switch SW_S. The photoelectric converter PD is, for example, a photodiode. When the switch SW_S is turned on, the transistor M2 operates as a source follower circuit in

conjunction with a current source I_c . A control node of the transistor M2 is connected to a node common to both the photoelectric converter PD and one of main nodes of the transistor M1. Then a voltage corresponding to the potential of this node appears at an output node of the source follower circuit. The potential of the control node of the transistor M2 varies with electric charge generated in the photoelectric converter PD. The transistor M1 resets the control node of the transistor M2 and the photoelectric converter PD in accordance with a voltage V_{RES} . The current source I_c may be common to the effective pixel 10 and other pixels including a light shielded pixel. The second reference pixel 31 may have the same configuration as that of the effective pixel 10. In the case of the second reference pixel 31, by keeping the transistor M1 in the on-state at least during the signal reading period, the potential of the control node of the transistor M2 is fixed and the second reference signal independent of the quantity of incident light is output.

FIG. 3B illustrates a configuration of the first reference pixel 30. The first reference pixel 30 has a configuration similar to that of the effective pixel 10, but differs from the effective pixel 10 in that a voltage supplied to the transistor M1 is V_W . The first and second reference pixels 30 and 31 may be configured such that the photoelectric converter PD is shielded from light, or may even have no photoelectric converter. In the first reference pixel 30, again, by keeping the transistor M1 in the on-state at least during the signal reading period, the potential of the control node of the transistor M2 is fixed and the

first reference signal independent of the quantity of incident light is output.

As described above, the photoelectric conversion device 1 of the present embodiment includes a reference pixel row, which contains a plurality of reference pixel pairs 33. This improves the accuracy of operation of the photoelectric conversion device 1. Also, a reference pixel pair 33 is disposed at an end of a reference pixel row, that is, at a scanning start position. This allows identification of the start position of the pixel row being read.

Second Embodiment

FIG. 4A illustrates a configuration of a reference pixel row according to a second embodiment of the present invention. A difference from the reference pixel row illustrated in FIG. 2A is that the reference pixel row illustrated in FIG. 4A contains temperature detecting pixels TP instead of the light shielded pixels 200. The temperature detecting pixels TP output signals having a signal level that corresponds to the temperature of the photoelectric conversion device 1.

FIG. 4B shows a transition of the value of a signal output from the output unit 600 when signals of a reference pixel row are read. Here, a description will be given of the case where signals are sequentially read from the left-hand side of FIG. 4A. As in the first embodiment, in the period from time T_0 to time T_4 , the first reference signal having an output level V_1 and the second reference signal having an output level V_2 are alternately output twice each. In the period from time T_4 to time T_{N-4} , a signal based on the temperature detecting pixels TP is output. Then,

in the period from time T_{N-4} to time T_N , the second reference signal and the first reference signal are alternately output twice each. As in the first embodiment, the output level V_2 of the second reference
5 signal may be substantially the same as that of the signal output from the light shielded pixels 200. An output level V_3 of the signal output from the temperature detecting pixels TP varies with the temperature of the photoelectric conversion device 1.

10 With the temperature detecting pixels TP of the present embodiment, a signal correction can be made in accordance with the temperature of the photoelectric conversion device 1.

The present embodiment can achieve effects similar
15 to those of the first embodiment.

Third Embodiment

FIG. 5 illustrates a configuration of the first and second reference pixels 30 and 31 according to a third embodiment of the present invention. In the
20 present embodiment, the first and second reference pixels 30 and 31 have the same circuit configuration.

The reference pixels according to the present embodiment are configured to be capable of switching an output between the first reference signal and the
25 second reference signal. In the embodiments described above, the control node of the transistor M2 of each of the first reference pixel 30 and the second reference pixel 31 is configured to be supplied with the voltage V_{RES} via the transistor M1. In the present embodiment,
30 the control node of the transistor M2 is configured to be further supplied with the voltage V_W via a

transistor M3. The transistor M1 and the transistor M3 are not simultaneously turned on.

Using the reference pixels described above is advantageous in that a pattern of a signal output from a reference pixel row can be changed.

The present embodiment can achieve effects similar to those of the embodiments described above.

Fourth Embodiment

FIG. 6 illustrates a configuration of an image pickup system according to a fourth embodiment of the present invention. An image pickup system 800 includes, for example, an optical unit 810, an image pickup element 890, a video signal processing unit 830, a recording/communicating unit 840, a timing control unit 850, a system control unit 860, and a reproducing/display unit 870. An image pickup apparatus 820 includes the image pickup element 890 and the video signal processing unit 830. The photoelectric conversion device 1 of the embodiments described above is used as the image pickup element 890.

The optical unit 810, which is an optical system such as a lens, focuses light from an object onto the pixel area PA having a plurality of two-dimensionally arranged pixels in the image pickup element 890 to form an image of the object. In accordance with timing based on a signal from the timing control unit 850, the image pickup element 890 outputs a signal corresponding to the light focused on the pixel area PA. The signal output from the image pickup element 890 is input to the video signal processing unit 830, and processed by the video signal processing unit 830 in accordance with a method defined by a program or the like. A signal

obtained by the processing in the video signal processing unit 830 is transmitted as image data to the recording/communicating unit 840. The recording/communicating unit 840 transmits the signal for forming an image to the reproducing/display unit 870 to cause the reproducing/display unit 870 to reproduce a moving image or display a still image. Also, in response to the signal from the video signal processing unit 830, the recording/communicating unit 840 not only communicates with the system control unit 860, but also records the signal for forming an image in a recording medium (not shown).

The system control unit 860 controls an overall operation of the image pickup system 800. The system control unit 860 controls the drive of the optical unit 810, the timing control unit 850, the recording/communicating unit 840, and the reproducing/display unit 870. The system control unit 860 has a storage device (not shown), such as a recording medium, in which a program and the like necessary for controlling the operation of the image pickup system 800 are recorded. The system control unit 860 supplies, into the image pickup system 800, a signal for switching the drive mode in accordance with a user operation or the like. For example, the signal for switching the drive mode is supplied for changing the row to be read or reset, changing the field angle in accordance with an electronic zooming operation, or shifting the field angle in accordance with an electronic image stabilizing operation. The timing control unit 850 controls the drive timing of the image pickup element 890 and the video signal processing unit 830 under control of the system control unit 860.

The image pickup system 800 may include, as the optical unit 810, a wavelength conversion member for converting a wavelength of incident light. Examples of the wavelength conversion member include one that emits
5 visible light upon incidence of X-rays. The image pickup element 890 generates a signal based on incident light having a wavelength converted by the wavelength conversion member. With this configuration, the image pickup system 800 serving as an X-ray imaging apparatus
10 can be provided. The image pickup system 800 may include an X-ray generating device serving as a light source that generates X-rays.

A plurality of semiconductor substrates, each having the photoelectric conversion device 1 thereon,
15 may be two-dimensionally arranged (in other words in a planar configuration) to form a multichip photoelectric conversion apparatus. The photoelectric conversion devices 1 forming the multichip photoelectric conversion apparatus may operate in parallel.

20 The embodiments described above are for illustrative purposes only, and changes can be made thereto without departing from the principles of the present invention. For example, in the embodiments described above, a reference pixel row contains the
25 light shielded pixels 200 or the temperature detecting pixels TP, as well as the reference pixel pairs 33. However, the reference pixel row may contain only reference pixels.

The present invention makes it possible to achieve
30 at least one of the following: improved accuracy of operation of a photoelectric conversion device, and

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identification of the start position of a pixel row
being read.

While the present invention has been described
with reference to exemplary embodiments, it is to be
5 understood that the invention is not limited to the
disclosed exemplary embodiments. The scope of the
following claims is to be accorded the broadest
interpretation so as to encompass all such
modifications and equivalent structures and functions.

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CLAIMS

1. A photoelectric conversion device comprising a pixel area including an effective pixel row and a reference pixel row, the reference pixel row including a plurality of reference pixel pairs, each pair including a first reference pixel and a second reference pixel arranged adjacent to each other, and a voltage supply unit;
- wherein the first reference pixel outputs a first reference signal independent of the quantity of incident light; and
- the second reference pixel outputs a second reference signal having a signal level different from a signal level of the first reference signal, the second reference signal being independent of the quantity of incident light, wherein each of the first reference pixels includes a transistor that outputs the first reference signal, and each of the second reference pixels includes a transistor that outputs the second reference signal, wherein the voltage supply unit supplies a first voltage to a gate of the transistor included in each of the first reference pixels, and supplies a second voltage to a gate of the transistor included in each of the second reference pixels, the second voltage has a different voltage from the first voltage.

2. The photoelectric conversion device according to claim 1, further comprising a scanning unit configured to scan the pixel area,

wherein the scanning unit first selects one of the reference pixel pairs in scanning of the reference

pixel row.

3. The photoelectric conversion device according to claim 2, wherein the scanning unit selects the first reference pixel of the reference pixel pair selected first.

4. The photoelectric conversion device according to claim 1, wherein the pixel area further includes a light shielded pixel row including light shielded pixels, each including a photoelectric converter shielded from light.

5. The photoelectric conversion device according to claim 4, wherein the signal level of the second reference signal is closer to a signal level of a signal based on the light shielded pixels than to the signal level of the first reference signal.

6. The photoelectric conversion device according to claim 4, wherein the signal level of the second reference signal is substantially the same as a signal level of a signal based on the light shielded pixels.

7. The photoelectric conversion device according to claim 1, wherein at least one of the plurality of reference pixel pairs is disposed at an end of the reference pixel row.

8. The photoelectric conversion device according to claim 7, wherein the first reference pixel and the second reference pixel of the at least one reference pixel pair are arranged in this order from the end; and

another of the plurality of reference pixel pairs is disposed at an opposite end opposite the end of the reference pixel row, and the first reference pixel and the second reference pixel of the reference pixel pair
5 at the opposite end are arranged in this order from the opposite end.

9. The photoelectric conversion device according to claim 1, wherein the reference pixel row further
10 includes at least one temperature detecting pixel that detects a temperature of the photoelectric conversion device.

10. The photoelectric conversion device according to claim 1, wherein the plurality of reference pixel
15 pairs are arranged adjacent to each other.

11. The photoelectric conversion device according to claim 1, wherein the first and second reference
20 pixels are configured to be capable of switching an output between the first and second reference signals.

12. A multichip photoelectric conversion apparatus formed by two-dimensionally arranging a plurality of
25 semiconductor substrates, each having the photoelectric conversion device according to claim 1.

13. An image pickup system comprising: the photoelectric conversion device according to claim 1;
30 and a video signal processing unit configured to process a signal output from the photoelectric conversion device to generate image data.

14. The image pickup system according to claim 13, further comprising a light source configured to generate X-rays.

5 15. The image pickup system according to claim 14, further comprising a wavelength conversion member configured to convert a wavelength of the X-rays.

10 16. A driving method of a photoelectric conversion device having a pixel area including an effective pixel row and a reference pixel row, the reference pixel row including a plurality of reference pixel pairs and a light shielded pixel, each pair including a first reference pixel and a second reference pixel arranged
15 adjacent to each other,

 wherein the first reference pixel outputs a first reference signal independent of the quantity of incident light, and the second reference pixel outputs a second reference signal having a signal level
20 different from a signal level of the first reference signal, the second reference signal being independent of the quantity of incident light, wherein each of the first reference pixels includes a transistor that outputs the first reference signal, and each of the
25 second reference pixels includes a transistor that outputs the second reference signal, wherein the driving method comprising: inputting a first voltage to a gate of the transistor included in each of the first reference pixels;

30 inputting a second voltage to a gate of the transistor included in each of the second reference pixels, the second voltage having a different voltage from the first voltage; and

outputting a signal from each of the first reference pixel and the second reference pixel included in one of the pairs before the light shielded pixel outputs a signal.

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17. The driving method of the photoelectric conversion device according to claim 16, wherein the signal level of the second reference signal is closer to a signal level of a signal based on light shielded pixels than to the signal level of the first reference signal, the light shielded pixels being included in a light shielded pixel row included in the pixel area, the light shielded pixels each including a photoelectric converter shielded from light.

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18. The driving method of the photoelectric conversion device according to claim 16, wherein the signal level of the second reference signal is substantially the same as a signal level of a signal based on light shielded pixels included in a light shielded pixel row included in the pixel area, the light shielded pixels each including a photoelectric converter shielded from light.

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19. The photoelectric conversion device according to claim 1, wherein the plurality of reference pixel pairs include a first reference pixel pair and a second reference pixel pair, the first reference pixel pair is adjacent to the second reference pixel pair, signal levels of the first reference signals of each of the first and second reference pixel pairs are the same, and wherein signal levels of the second reference signals of each of the first and second reference pixel

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pairs are the same.

20. The photoelectric conversion device according to claim 19, wherein the second reference pixel of the first reference pixel pair is arranged adjacent to the first reference pixel of the second reference pixel pair.

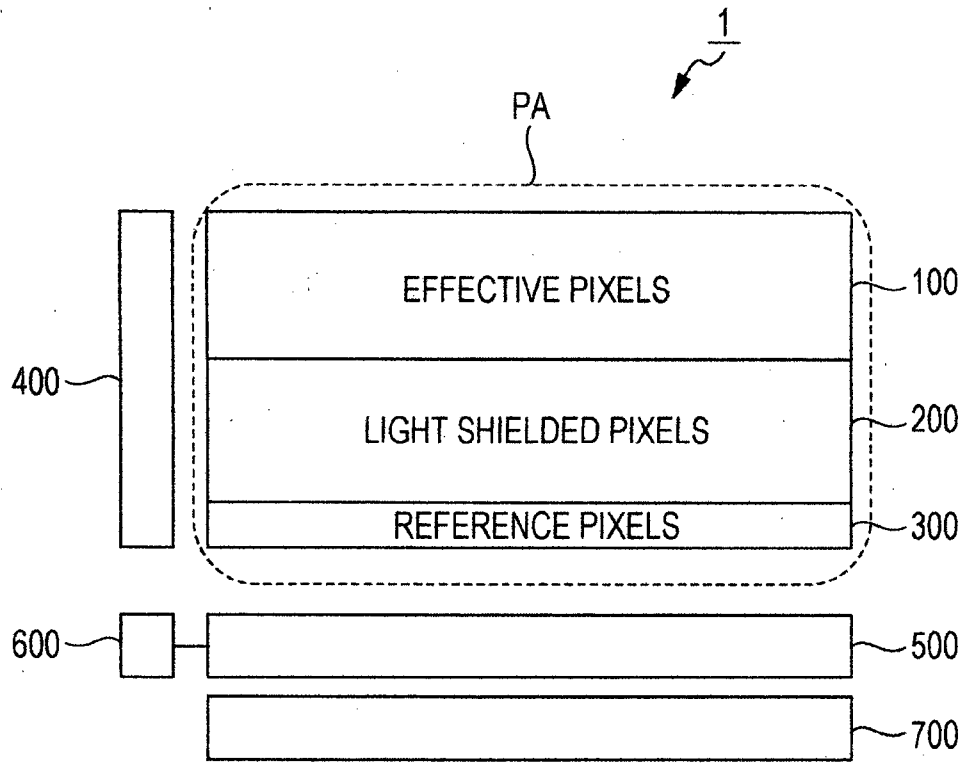
21. A photoelectric conversion device comprising a pixel area including an effective pixel row and a reference pixel row, the reference pixel row including a plurality of reference pixel pairs, each pair including a first reference pixel and a second reference pixel arranged adjacent to each other, wherein the first reference pixel outputs a first reference signal independent of the quantity of incident light; and the second reference pixel outputs a second reference signal having a signal level different from a signal level of the first reference signal, the second reference signal being independent of the quantity of incident light, wherein the first and second reference pixels are configured to be capable of switching an output between the first and second reference signals.

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FIG. 1



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Applicant

By:

C. RISEL *[Signature]* CASTILLO-TALEON

FIG. 2A

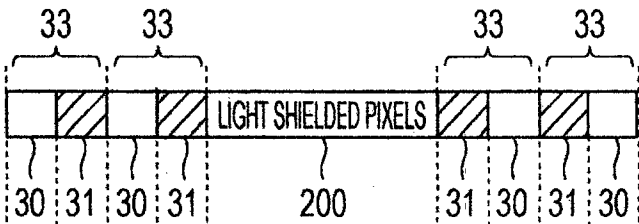
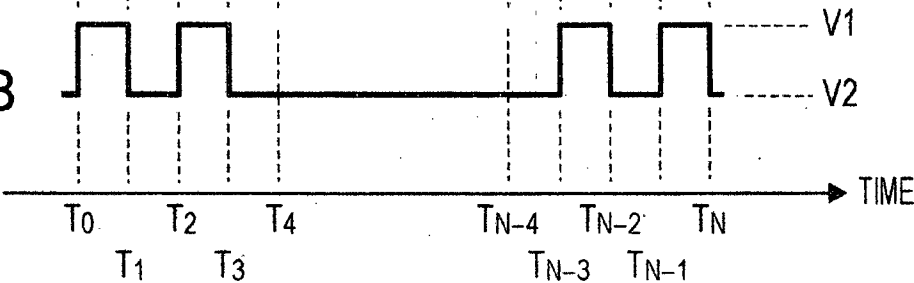


FIG. 2B



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FIG. 3A

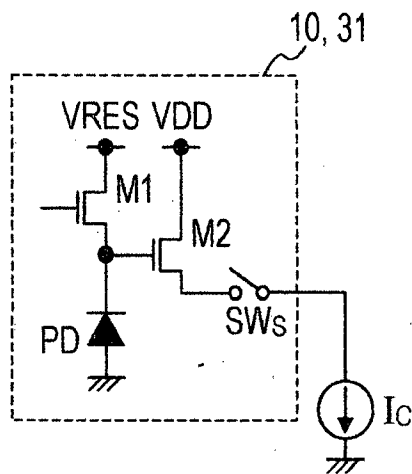
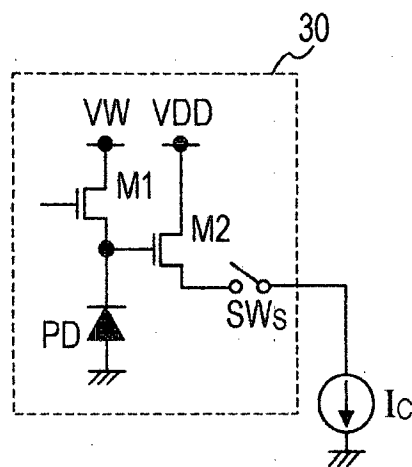


FIG. 3B



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FIG. 4A

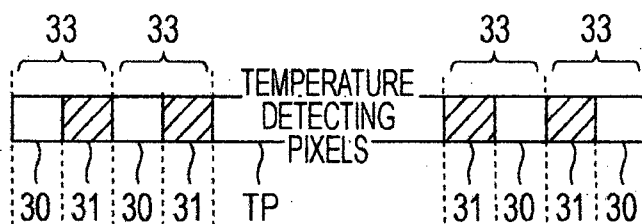
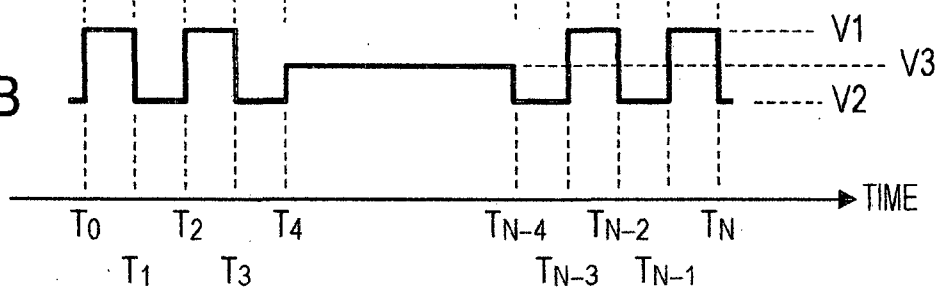


FIG. 4B

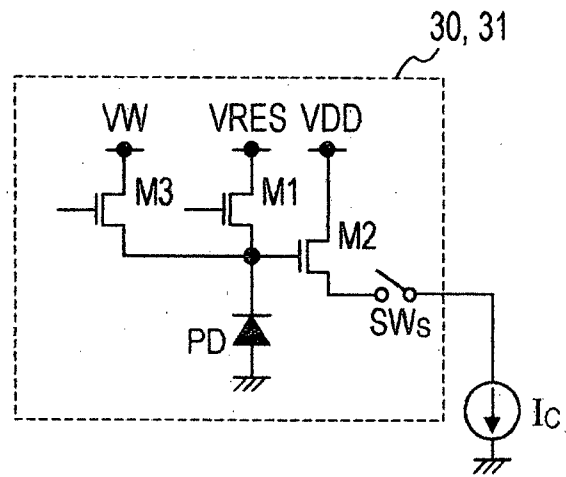


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FIG. 5



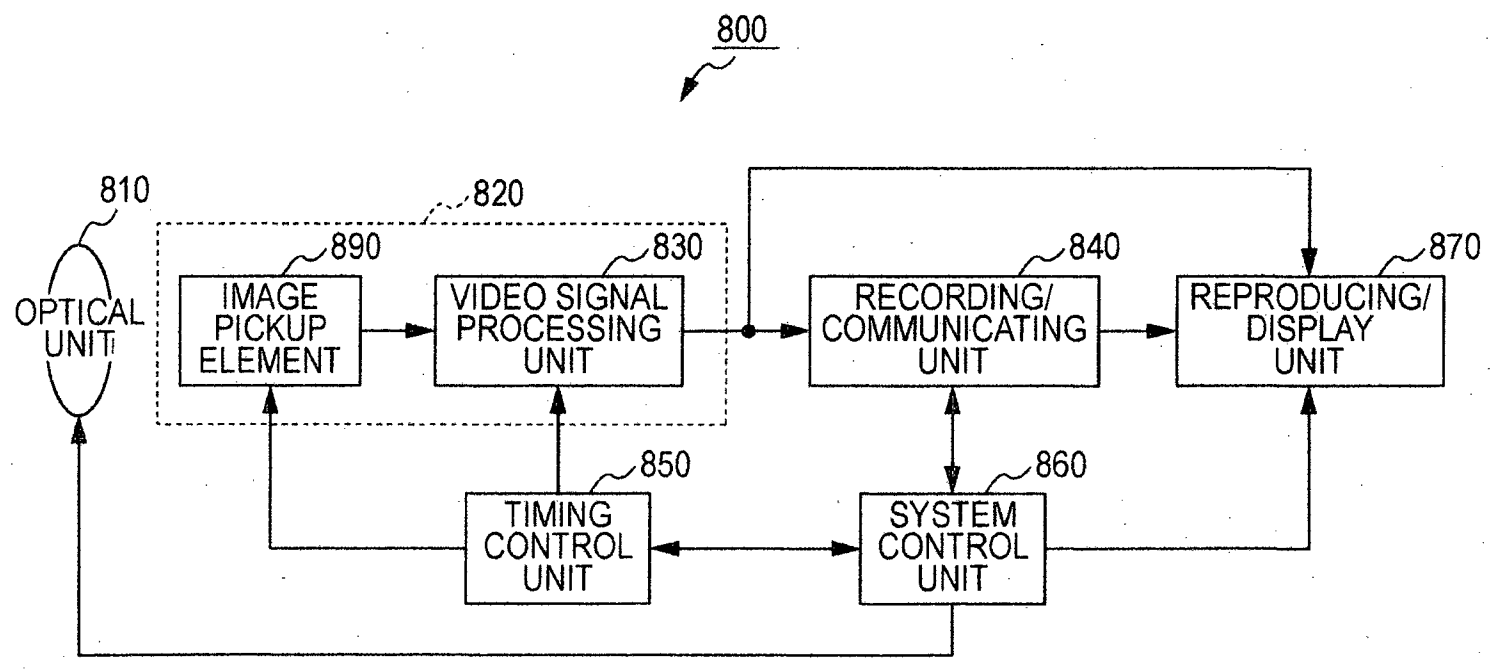
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FIG. 6



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